

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In repatent application of

Docket No.: P27191

Douglas D. COOLBAUGH et al.

Confirmation No. 1904

Serial No.: 10/707,905

Group Art Unit: No. 2811

Filed: January 23, 2004

Examiner: Shouxiang Hu

For: STRUCTURE AND METHOD FOR HYPER-ABRUPT JUNCTION VARACTORS

Commissioner for Patents U.S. Patent and Trademark Office Customer Window, Mail Stop AF Randolph Building **401 Dulany Street** Alexandria, VA 22314

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to applicant's duty of disclosure under 37 CFR §1.56, applicant respectfully brings the following documents, listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. Applicant respectfully requests that the Examiner consider the materials cited and indicate such consideration by appropriately initialing the enclosed PTO-1449 Form and including a copy of the initialed form in the next official communication.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which the applicant is aware.

P27191.A05

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

Respectfully submitted, Douglas D. COQLBAUGH

Andrew M. Calderon Registration No.38,093

November 29, 2005 GREENBLUM & BERNSTEIN, P.L.C. 1950 Roland Clarke Place Reston, VA 20191 (703) 716-1191

FORM PTO-	U.S. Department of Commerce Patent and Trademark Office								Atty. Docket No. BUR920030177US1			Application No. 10/707,905				
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		ļ	Energy Si, S, and Si/S Implantation for Application to Microwave Devices", Journal of Electronic													
	ļ	<u> </u>	Ma	ateri	als,	Vol.	22,	No.	1, 1993, pp	. 73-80						
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